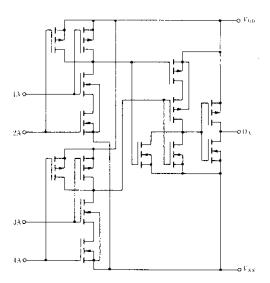
HD14012B

Dual 4-input NAND Gate

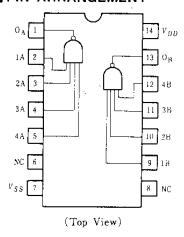
FEATURES

- Quiescent Current = 0.5nA typ/pkg @5V
- Noise Immunity = 45% of V_{DD} typ
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for Pin Replacements for CD4012B and MC14012B Series

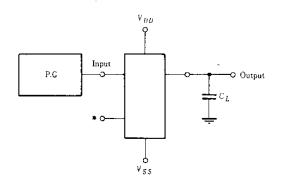
ECIRCUIT SCHEMATIC (1/2)



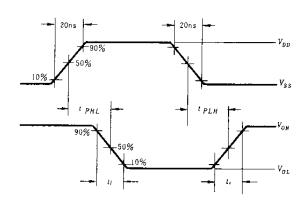
PIN ARRANGEMENT



■ SWITCHING TIME TEST CIRCUIT



* All unused inputs of AND, NAND gates must be connected to V_{BB} .



■ ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	<u> </u>	Test Conditions	- 40°C		25℃		85°C		Unit	
	55,11001	$V_{DD}(V)$.	min	max	min	typ	max	min	max	l	
		5.0	$V_{ta} = V_{DD}$		0.05	_	0	0.05	-	0.05	v
	Vol	10		_	0.05	_	0	0.05	-	0.05	
		15		-	0.05	_	0	0.05	-	0.05	
Output Voltage		5.0	$V_{in} = 0$	4.95	_	4.95	5.0	-	4.95	_	v
	V_{OH}	10		9.95	_	9.95	10	_	9.95	_	
		15		14.95		14.95	15	_	14.95	_	
150		5.0	$V_{out}=4.5\mathrm{V}$	<u> </u>	1.5	_	2.25	1.5		1.5	v
	V_{IL}	10	$V_{out} = 9.0 \text{V}$	_	3.0	-	4.50	3.0	_	3.0	
Input Voltage .		15	$V_{out} = 13.5 \mathrm{V}$	_	4.0	-	6.75	4.0		4.0	
input voitage .		5.0	$V_{out} = 0.5 \text{V}$	3.5	_	3.5	2.75	_	3.5	_	v
	V_{IH}	10	$V_{out} = 1.0 \mathrm{V}$	7.0	_	7.0	5.50	-	7.0	- '	
	!	15	$V_{out} = 1.5 \text{V}$	11.0	-	11.0	8.25		11.0		
	Іон	5.0	$V_{OH}=2.5\mathrm{V}$	-2.5	_	-2.1	-4.2		-1.7		mA
		5.0 j	$V_{OH} = 4.6 \text{V}$	-0.52	-	-0.44	-0.88	_	-0.36		
		10	$V_{OH} = 9.5 \text{V}$	-1.3	_	-1.1	-2.25		-0.9		
Output Drive Current		15	$V_{OH}=13.5\mathrm{V}$	-3.6		-3.0	-8.8		-2.4		
	I ₀₁ .	5.0	$V_{OL} = 0.4 \text{V}$	0.52	-	0.44	0.88	_	0.36		mA
		10	$V_{OL} = 0.5 \text{V}$	1.3	_	1.1	2.25	-	0.9	. –	
		15	$V_{OL}=1.5V$	3.6	_	3.0	8.8	_	2.4	_	
Input Current	Iin	15		· –	±0.3		±0.00001	±0.3	-	±1.0	μ A
Input Capacitance	Cin		$V_{in}=0$			_	5.0	7.5	_		рF
Quiescent Current	IDD	5.0	Zero Signal, per Package	_	1.0		0.0005	1.0	_	7.5	<u>μ</u> Α
		10			2.0		0.0010	2.0	_	15.0	
		15			4.0	<u> </u>	0.0015	4.0		30.0	
•	Iτ	5.0	Dynamic $+I_{DD}$, $C_L = 50$ pF	_	_		0.3		-	-	μΑ
Total Supply Current*		10	per Gate, f=1kHz	_	_		0.6	-		_	
		15	F zanoji surm	-	! –	-	0.9		i –	_	

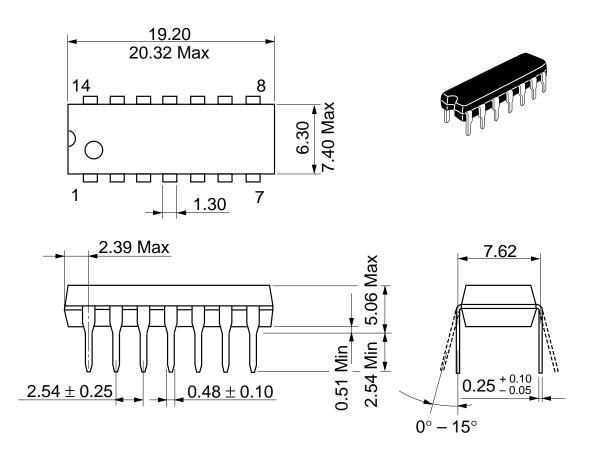
^{*} To calculate total supply current at frequency other than lkHz.

SWITCHING CHARACTERISTICS $(C_L = 50 \text{pF}, T_a = 25^{\circ}\text{C})$

Characteristic	Symbol	$V_{DD}(\mathbf{V})$	min	typ	max	Unit
Output Rise Time	t,	5.0	_	100	200	·
		10	_	50	100	ns
		15		40	80	
Output Fall Time		5.0		100	200	ns
	t _f	10	_	50	100	
		15	_	40	80	
Propagation Delay Time	tplh	5.0	_	160	320	~
		10	-	65	130	ns
		15	_	50	100	
	tрнL	5.0		160	320	
		10		65	130	ns
		15	_	50	100	1

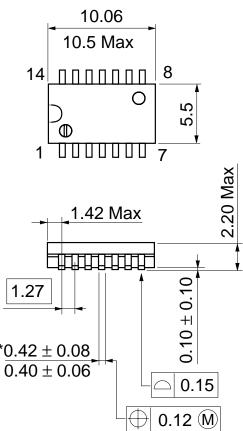
 $⁼ V_{DD} = 5.0V \quad h = (0.3 \mu \text{A}/\text{kHz}) f + f_{DD}/2 \qquad \text{if } V_{DD} = 10V \quad h = (0.6 \mu \text{A}/\text{kHz}) f + f_{DD}/2 \qquad \text{if } V_{DD} = 15V \quad h = (0.9 \mu \text{A}/\text{kHz}) f + f_{DD}/2$

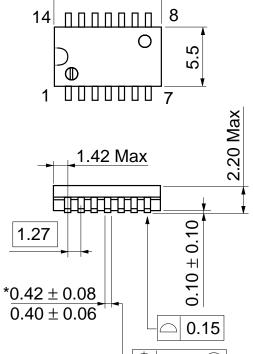
Unit: mm



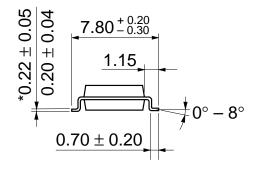
Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

Unit: mm





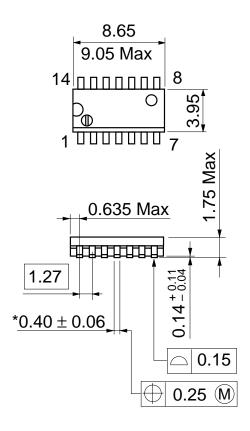




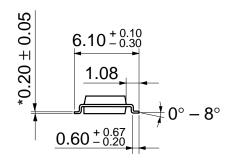
Hitachi Code	FP-14DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.23 g

Dimension	including	the	plating	thickness
Bas	se materia	al dir	mensioi	1

Unit: mm







Hitachi Coo	de	FP-14DN	
JEDEC		Conforms	
EIAJ		Conforms	
Weight (refe	erence value)	0.13 g	

*Pd plating

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